

SPICE Device Model Si8413DB Vishay Siliconix

P-Channel 20-V (D-S) MOSFET

CHARACTERISTICS

- P-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS

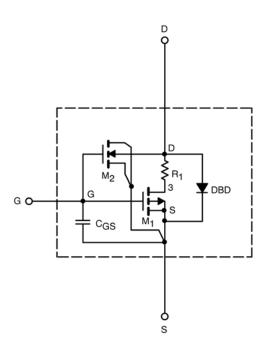
- Apply for both Linear and Switching Application
- Accurate over the -55 to 125°C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

DESCRIPTION

The attached spice model describes the typical electrical characteristics of the p-channel vertical DMOS. The subcircuit model is extracted and optimized over the -55 to 125° C temperature ranges under the pulsed 0-V to 5-V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

SUBCIRCUIT MODEL SCHEMATIC

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched C_{gd} model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.



This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.



SPECIFICATIONS (T _J = 25°C UNLESS OTHERWISE NOTED)					
Parameter	Symbol	Test Condition	Simulated Data	Measured Data	Unit
Static			-		
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = -250 \ \mu A$	0.91		V
On-State Drain Current ^a	I _{D(on)}	V_{DS} = -5 V, V_{GS} = -4.5 V	103		А
Drain-Source On-State Resistance ^a	r _{DS(on)}	V_{GS} = -4.5 V, I _D = -1 A	0.038	0.0393	Ω
		V_{GS} = -2.5 V, I _D = -1 A	0.053	0.052	
Forward Transconductance ^a	g _{fs}	$V_{DS} = -10 V$, $I_{D} = -1 A$	7.4	7.4	S
Diode Forward Voltage ^a	V _{SD}	$I_{\rm S}$ = -1 A, $V_{\rm GS}$ = 0 V	-0.78	-0.80	V
Dynamic ^b			•		
Total Gate Charge	Qg	V_{DS} = -10 V, V_{GS} = -4.5 V, I_{D} = -1 A	11	14	nC
Gate-Source Charge	Q _{gs}		1.7	1.7	
Gate-Drain Charge	Q _{gd}		5.1	5.1	
Turn-On Delay Time	t _{d(on)}	V_{DD} = -10 V, R _L = 10 Ω I _D \cong -1 A, V _{GEN} = -4.5 V, R _G = 6 Ω	55	31	ns
Rise Time	tr		40	50	
Turn-Off Delay Time	t _{d(off)}		186	105	
Fall Time	t _f		47	90	

Notes

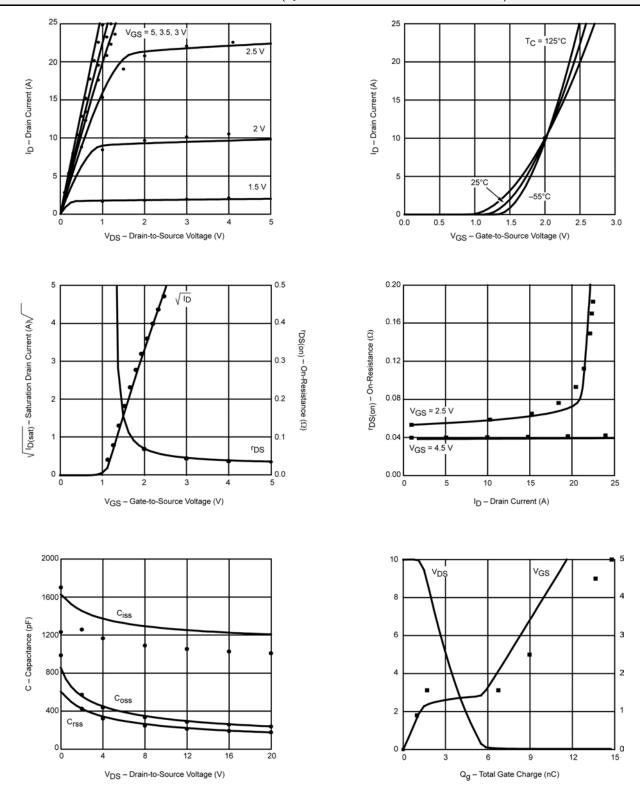
a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2%. b. Guaranteed by design, not subject to production testing.



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COMPARISON OF MODEL WITH MEASURED DATA (TJ=25°C UNLESS OTHERWISE NOTED)



Note: Dots and squares represent measured data.



Vishay

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